

High Power PIN Diodes

V16

MA4P1000 Series Electrical Specifications @ T_A = +25°C

Part # (NM Indicates Non- Magnetic)	Total Capacitance pF V _R = 50 V, 1 MHz		pacitance Reverse Voltage Ser VDC		erse Voltage Series Resistance W		R _P Parallel Resistance kW V _R = 0 V, 100 MHz
	Тур.	Max.	Min.	Max.	Тур.	Max.	Min.
MA4P1200 - 401T	1.2	1.5					
MA4P1200NM - 401T	1.2	1.5					
MA4P1250 -1072T	0.8	1.2	50	100	0.5	0.75	5
MA4P1250NM -1072T	0.8	1.2					
MA4P1450 -1091T	1.8	2.5					

Part #	Forward	/ _F I Voltage _{ward} @ 1V ≤	T _∟ Carrier Lifetime		Harmonic	rd Bias Distortion * R(3a/a)	Reverse Bias Harmonic Distortion R(2a/a) – R(3a/a)				
(NM Indicates Non- Magnetic)	I _F = 5	0 mA	I _F = 10 mA, I _R = 6 mA		I _F = 10 mA, I _R = 6 mA P _{IN} = 30 W, 100 MHz P _{IN} = 10 mA					0 dBm, V _R = 0 V, 100 MHz	
	Тур.	Max.	Min.	Тур.	Min.	Тур.	Min.	Тур.			
MA4P1200 - 401T											
MA4P1200NM - 401T											
MA4P1250 -1072T	0.85	1.0	2	8	80	90	60	70			
MA4P1250NM-1072T											
MA4P1450 -1091T											

^{*}Notes

Power Dissipation and Thermal Resistance Ratings @ T_A = +25°C

Package	Condition	MA4P1200(NM)-401T		MA4P1250	(NM)-1072T	MA4P1450-1091T		
Style	Condition	P _{DISS}	θ _{JC}	P _{DISS}	θ _{JC}	P _{DISS}	θ _{JC}	
В	No Heatsink	1.5 W	15°C/W	_	_	_	_	
Axial Lead	Lead Length 1/4"	5.5 W	15 C/VV	_	_	_	_	
F	No Heatsink	-	_	6 W	15°C/W	10 W	5°C/W	
MELF	Infinite Heatsink	-	_	18 W	15 C/VV	30 W	5 C/VV	

^{1.) &}quot;NM" in the base part number signifies non-magnetic package.

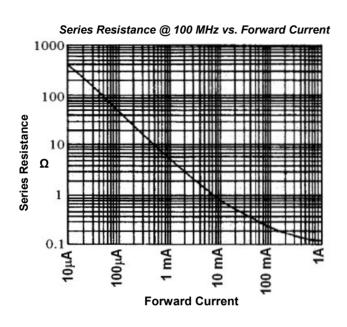
^{2.) &}quot;T" suffix denotes tape and reel

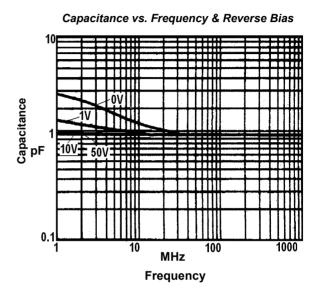


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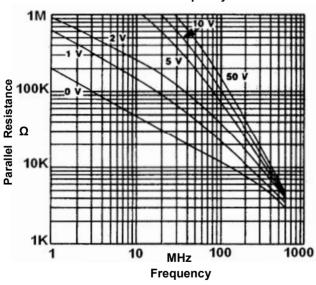
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Typical Performance Curves @ T_A = +25°C MA4P1200 Series

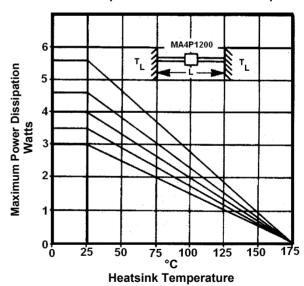




Parallel Resistance vs. Frequency & Reverse Bias



Heatsink Temperature vs. Max. Power Dissipation



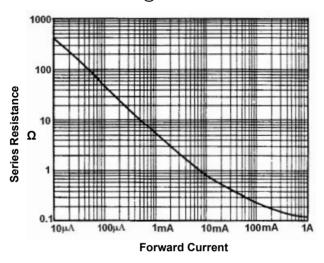


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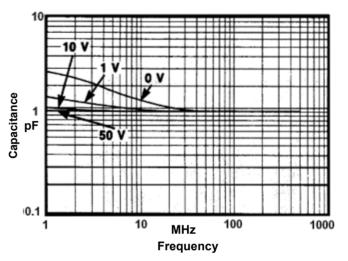
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Typical Performance Curves @ $T_A = +25$ °C MA4P1250 Series

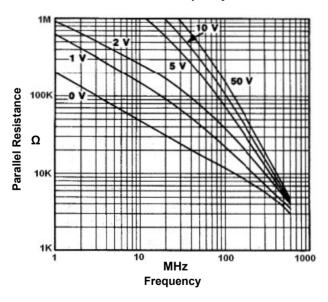
Series Resistance @ 100 MHz vs. Forward Current



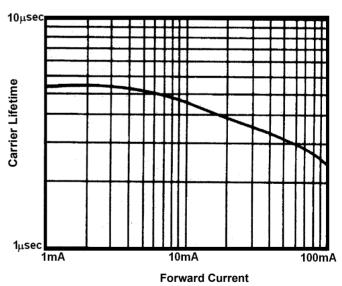
Capacitance vs. Frequency & Reverse Bias



Parallel Resistance vs. Frequency & Reverse Bias



Carrier Lifetime vs. Forward Bias Current



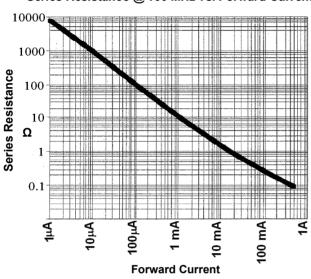


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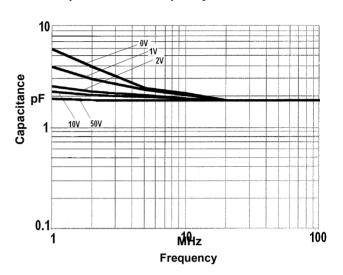
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Typical Performance Curves @ $T_A = +25$ °C MA4P1450 Series

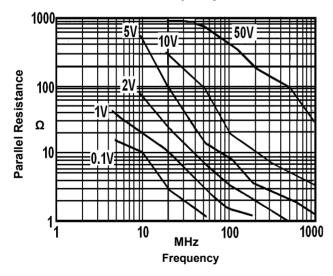
Series Resistance @ 100 MHz vs. Forward Current



Capacitance vs. Frequency and Reverse Bias



Parallel Resistance vs. Frequency and Reverse Bias





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MA4P4000 - MA4P7100 Series Electrical Specifications @ T_A = +25°C

Parameter	Symbol	Condition	MA4P4000 Series	MA4P4300 Series	MA4P7000 Series	MA4P7100 Series
Maximum Series Resistance	Rs	I _F = 100 mA	0.5 Ω	1.0 Ω	0.9 Ω	0.5 Ω
Maximum Total Capacitance	C _T	V _R = 100 V	2.2 pF	2.0 pF	0.7 pF	1.0 pF
Minimum Parallel Resistance	R₽	V _R = 100 V	20 kΩ	50 kΩ	200 kΩ	100 kΩ
Minimum Carrier Lifetime	TL	I _F = 10 mA	20 μs	15 µs	5 µs	2.5 µs
Maximum Forward Voltage	V _F	I _F = 100 mA	1.0 V	1.2 V	1.0 V	1.0 V
Maximum Reverse Current	I _R	At max. rated voltage	1 μΑ	1 μΑ	1 μΑ	1 μΑ
Nominal I-Region Width	μ	_	175 µm	300 µm	175 µm	100 µm

Maximum Reverse Voltage Rating (V_R)

Maximum Reverse Voltage Rating	MA4P4000 Series	MA4P4300 Series	MA4P7000 Series	MA4P7100 Series
100 V	MA4P4001B-402 MA4P4001BNM-402 MA4P4001F-1091T	MA4P4301B-402 MA4P4301F-1091T	MA4P7001F-1072T	MA4P7101B-401T MA4P7101F-1072T
200 V	MA4P4002B-402 MA4P4002F-1091T	MA4P4302B-402	MA4P7002B-401T MA4P7002F-1072T	MA4P7102B-401T MA4P7102F-1072T
400 V	_	_	_	MA4P7104B-401T MA4P7104F-1072T
600 V	MA4P4006F-1091T MA4P4006B-402	_	MA4P7006B-401T MA4P7006F-1072T	_

^{*}Notes:

^{2.) &}quot;T" suffix denotes tape and reel.

Package Style	Condition		Condition Selies		MA4P4300 Series		MA4P7000 Series		MA4P7100 Series	
Otyle		P _{DISS}	θ _{JC}	P _{DISS}	θ _{JC}	P _{DISS}	θ _{JC}	P _{DISS}	θ _{JC}	
В	1/4" Lead Length	12 W	12.5°C/W	10 W	15°C/W	5 W	30°C/W	6 W	25°C/W	
Axial Leaded	No Heatsink	2.5 W	_	2.5 W		1.5 W	_	1.5 W	_	
F MELF	Infinite Heatsink	7.5 W	20°C/W	5 W	30°C/W	10 W	15°C/W	11.5 W	13°C/W	
Both B and F	Single 1 µs pulse	100 kW	_	100 kW	_	15 kW	_	15 kW	_	
Both B and F	Single 100 µs	5 kW	0.03°C/W	5 kW	0.03°C/W	300 W	0.5°C/W	300 W	0.5°C/W	

^{1.) &}quot;NM" in the base part number signifies non-magnetic package.

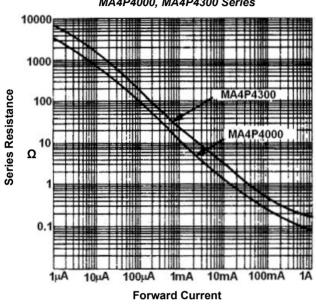


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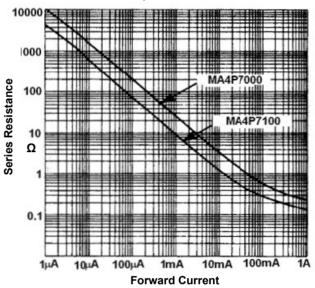
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Typical Performance Curves @ T_{AMB} = +25°C MA4P4000,MA4P4300, MA4P7000, MA4P7100 Series

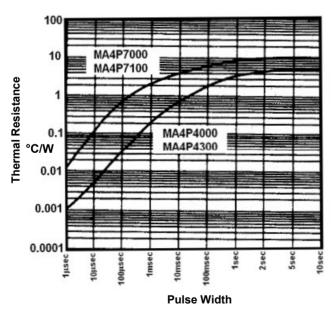
Series Resistance at 100 MHz vs. Forward Current MA4P4000. MA4P4300 Series



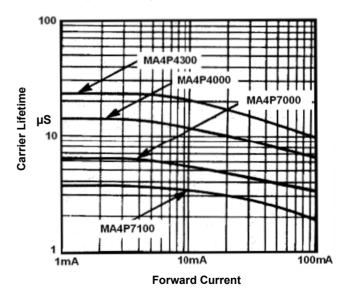
Series Resistance at 100 MHz vs. Forward Current MA4P7000, MA4P7100 Series



Thermal Resistance vs. Pulse Width MA4P4000, MA4P4300, MA4P7000 & MA4P7100 Series



Carrier Lifetime vs. Forward Bias Current MA4P4000, MA4P4300, MA4P7000 & MA4P7100 Series



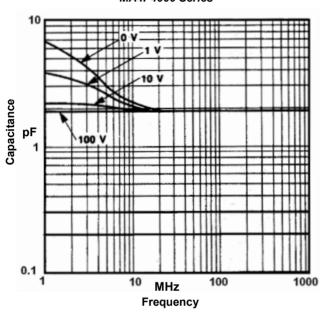


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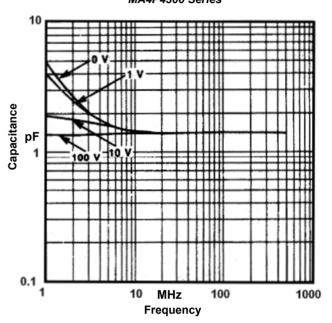
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Typical Performance Curves @ T_{AMB} = +25°C MA4P4000, MA4P4300, MA4P7000, MA4P7100 Series

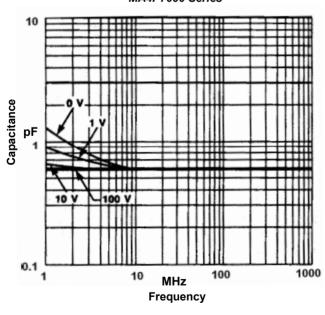
Capacitance vs. Frequency & Reverse Bias MA4P4000 Series



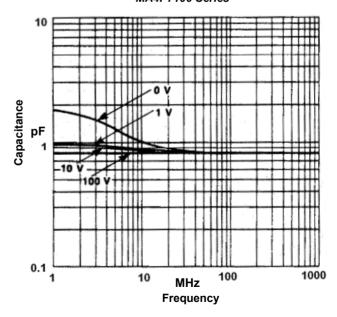
Capacitance vs. Frequency & Reverse Bias MA4P4300 Series



Capacitance vs. Frequency & Reverse Bias MA4P7000 Series



Capacitance vs. Frequency & Reverse Bias MA4P7100 Series



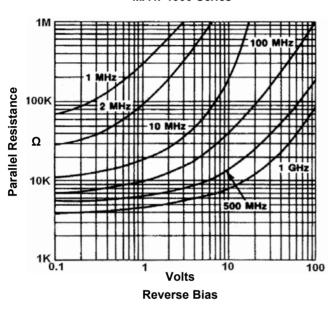


High Power PIN Diodes

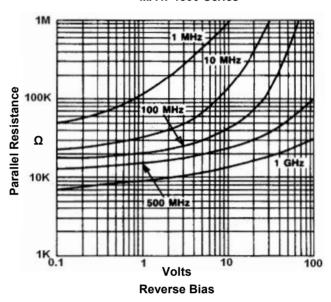
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Typical Performance Curves @ T_{AMB} = +25°C MA4P4000, MA4P4300, MA4P7000, MA4P7100 Series

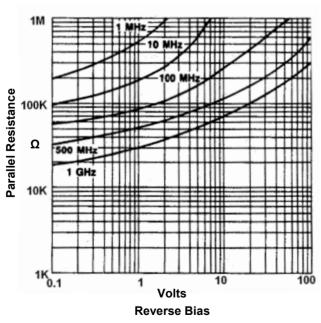
Parallel Resistance vs. Reverse Bias & Frequency
MA4P4000 Series



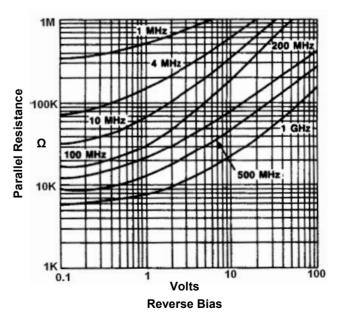
Parallel Resistance vs. Reverse Bias & Frequency
MA4P4300 Series



Parallel Resistance vs. Reverse Bias & Frequency
MA4P7000 Series



Parallel Resistance vs. Reverse Bias & Frequency MA4P7100 Series



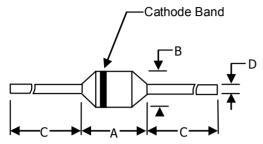


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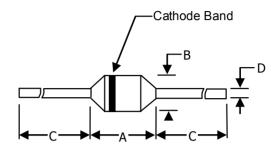
Case Styles

401 Axial Leaded Packages



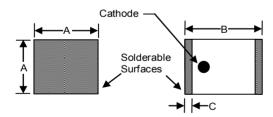
401 Package (tape and reel only)	Dimensior	INC	HES	М	М
500 or 1000 pcs/reel specify when ordering	sion	Min.	Max.	Min.	Max.
MA4P1200-401T	Α	_	0.130	_	3.30
MA4P1200NM-401T MA4P7002B-401T	В	_	0.090	_	2.29
MA4P7006B-401T MA4P7101B-401T MA4P7102B-401T	С	0.975		24.77	
MA4P7104B-401T	D	0.027	0.029	0.69	0.74

402 Axial Leaded Packages



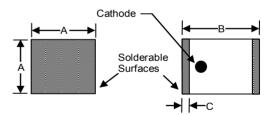
402 Package (bulk only)	Dimens	Dimension Min. MAX		ES MM	
100 pcs/bag	ion	Min.	MAX	Min.	Max.
MA 4D 400 4D 400	Α	_	0.230		5.84
MA4P4001B-402 MA4P4001BNM-402 MA4P4002B-402	В	_	0.140	_	3.56
MA4P4006B-402 MA4P4301B-402	С	0.975		24.77	
MA4P4302B-402	D	0.039	0.041	0.99	1.04

1091 MELF Surface Mount Packages



1091 Package (tape and reel only)	Dimension	INC	HES	N	IM
500 pcs/reel	ion	Min.	Max.	Min.	Max.
MA4P1450-1091T	Α	0.138	0.155	3.51	3.94
MA4P4001F-1091T MA4P4002F-1091T MA4P4006F-1091T	В	0.181	0.191	4.57	4.85
MA4P4301F-1091T	С	0.011	0.026	0.279	0.660

1072 MELF Surface Mount Packages



1072 Package (tape and reel only)	Dimension	INC	HES	М	М
1500 or 5000 pcs/reel specify when ordering	ion	Min.	Max.	Min.	Max.
MA4P1250-1072T MA4P1250NM-1072T	Α	0.080	0.095	2.032	2.413
MA4P7001F-1072T MA4P7002F-1072T MA4P7006F-1072T	В	0.115	0.125	2.921	3.175
MA4P7101F-1072T MA4P7104F-1072T	С	0.008	0.023	0.203	0.584



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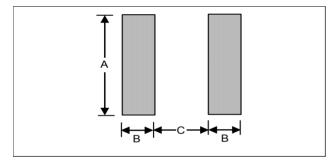
MELF Assembly Recommendations

Devices may be soldered using standard 60Sn/40Pb or RoHS compliant solders. Axial leads and solderable surfaces of MELF devices are tin plated 50 µm thick to ensure an optimum connection.

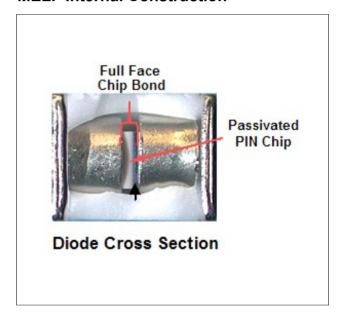
For recommended Sn/Pb and RoHS soldering profiles See Application Note M538 on the MACOM website.

Circuit Pad Layout for MELF Diodes

Dimension	107	72	1091			
	inches	mm	inches	mm		
А	0.093	2.36	0.150	3.81		
В	0.050	1.27	0.050	1.27		
С	0.060	1.52	0.100	2.54		



MELF Internal Construction



Ordering Information

MELF diodes are available in tape and reel in quantities as shown in table below

Package Style	Quantity (7" Reel)	Bulk Devices Per Bag
1072T	1500 or 5000	N/A
1091T	500	N/A

Tape and reel information can be found in application note M513 the MACOM website.



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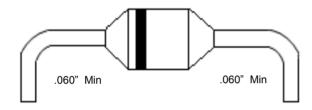
Axial Leaded HIPAX Assembly Recommendations

Bends on case styles 401 and 402, axially leaded devices, must be made while holding the lead firm and forming the bend no closer than .060 inches from the body of the part. Bending the lead <0.060 inches from the body of the part is not recommended and may cause internal damage to the chip. Appropriate fixturing should be used.

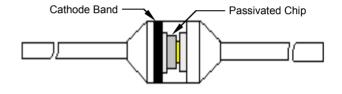
Devices may be soldered using standard 60Sn/40Pb or any RoHS compliant solders. Axial leads are tin plated $50 \mu m$ thick to ensure an optimum connection.

For recommended Sn/Pb and RoHS soldering profiles see Application Note M538 on the MACOM website.

Case Style 401 & 402 Minimum Bend Distance



Case Style 401 & 402 Internal Construction



Ordering Information

Axial leaded diodes are available in tape and reel or bulk in quantities shown in the table below

Package Style	Quantity Per Reel	Bulk Devices Per Bag
401T	500 or 1000 (specify qty. when ordering)	N/A
402	N/A	100

Environmental Ratings

HIPAX PIN diodes are designed to meet most environmental and electrical requirements and may be ordered screened to MIL-STD-750 specifications as described in the table below.

TEST	METHOD	DESCRIPTION/ CONDITIONS
Moisture Resistance	1021	85°C, 85% Relative Humidity, 168 hrs
High Temperature Storage	1031	+175°C , 250 Hours
HTRB	1038	80% of rated V _R , 50°C, 96 Hours
Temperature Shock	1051	-65°C to +175°C, 20 Cycles
Fine Leak	1071 Cond. H	1 x 10 ⁻⁷ CC/Sec
Constant Acceleration	2006	20,000 G's
Solderability	2026	IPC/JDEC J-STD-02
Tension ¹	2036.3 Cond. A	2 Lbs., 30 Seconds
Lead Fatigue ¹	2036.3 Cond. E	3 Cycles, 8 oz., 90°,

Note:

¹⁾ Test applicable to HIPAX axially leaded devices only.



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MA4P1200NM-401T MA4P1250NM-1072T MA4P1250-1072T MA4P4006F-1091T MA4P4301F-1091T

MA4P7001F-1072T MA4P7006F-1072T MA4P7102F-1072T MA4P7104F-1072T MA4P4002B-402 MA4P4001F
1091T MA4P1450-1091T MA4P4002F-1091T MA4P4001B-402 MA4P7002F-1072T MA4P7436CA-287T

MA4P7433ST-1146T MA4P7464F-1072T MA4P7101F-1072T MA4P7104B-401 MA4P4301B-402 MA4PK3000-1252

MA4P7438-287T MA4P7438CA-287T MA4P7455-287T MA4P7455CA-1146T MA4P7455ST-287T MA4P7493-134

MA4P4006B-402 MA4P7102B-401T MA4P7104B-401T MA4P7436-1141T MA4P7437-1141T MA4P7437-287T